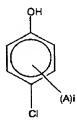
WHAT IS CLAIMED IS:

1. An aromatic liquid-crystalline polyester solution composition comprising 100 parts by weight of a solvent (A) and 0.01 to 100 parts by weight of an aromatic liquid-crystalline polyester (B), wherein said solvent (A) is a solvent containing 30% by weight or more of a chlorine-substituted phenol compound represented by the following general formula (I):



(I)

wherein A represents a hydrogen atom, a halogen atom or a tri-halogenated methyl group, and i represents an integer of 1 or more and 4 or less.

2. The aromatic liquid-crystalline polyester solution composition according to claim 1, wherein the aromatic liquid-crystalline polyester comprises 30 to 80% by mole of a structural unit derived from p-hydroxybenzoic acid, 10 to 35% by mole of a structural unit derived from at least one compound selected from the group consisting of hydroquinone, resorcinol, 4,4'-dihydroxybiphenyl, bisphenol A and bisphenol S, and 10

to 35% by mole of a structural unit derived from at least one compound selected from the group consisting of terephthalic acid, isophthalic acid and naphthalenedicarboxylic acid.

- 3. The aromatic liquid-crystalline polyester solution composition according to claim 2, wherein the content of a structural unit derived from isophthalic acid is 0.5 mole or more when the total molar number of structural units derived from at least one compound selected from the group consisting of terephthalic acid, isophthalic acid and naphthalenedicarboxylic acid is taken as 1.
- 4. An aromatic liquid-crystalline polyester film obtained by casting an aromatic liquid-crystalline polyester solution composition according to claim 1 and removing said solvent (A).
- 5. A process for producing an aromatic liquid-crystalline polyester film which comprises the steps of casting an aromatic liquid-crystalline polyester solution composition according to claim 1, and removing said solvent (A).
- 6. The aromatic liquid-crystalline polyester solution composition according to claim 1, wherein further comprises 1 to 100 parts by weight of an inorganic filler (C) in addition to the solvent (A) and the aromatic liquid-crystalline polyester (B).
 - 7. The aromatic liquid-crystalline polyester solution

composition according to claim 6, wherein the inorganic filler (C) is a silica having an average particle diameter of 0.1 μm or more and 10 μm or less.

- 8. A multilayer print circuit board comprising an insulating layer containing an aromatic liquid-crystalline polyester solution composition according to claim 6 formed on a substrate having a circuit pattern, and another circuit pattern formed on said insulating layer so as to electrically communicate with the former circuit pattern.
- 9. A process for producing a multilayer print circuit board, wherein the process comprises the steps of forming an insulating layer containing an aromatic liquid-crystalline polyester solution composition according to claim 6 on a substrate having a circuit pattern, and forming another circuit pattern on said insulating layer so as to electrically communicate with the former circuit pattern.
- 10. The aromatic liquid-crystalline polyester solution composition according to claim 1, wherein further comprises 0.2 to 200 parts by weight of a dielectric powder in addition to the solvent (A) and the aromatic liquid-crystalline polyester (B).
- 11. The aromatic liquid-crystalline polyester solution composition according to claim 10, wherein the dielectric powder is at least one dielectric powder selected from the group consisting of barium titanate, strontium titanate, a solid

solution of barium titanate and strontium titanate, and tantalum oxide.

- 12. The aromatic liquid-crystalline polyester solution composition according to claim 10, wherein the dielectric powder is added in an amount of 0.2 to 200 parts by weight per 100 parts by weight of the aromatic liquid-crystalline polyester solution composition according to claim 1.
- 13. A dielectric membrane obtained by applying the aromatic liquid-crystalline polyester solution composition according to claim 10 on a substrate.